

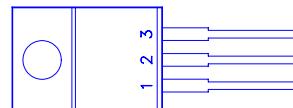
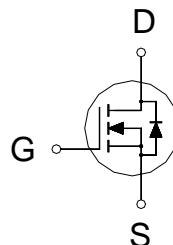
**NIKO-SEM**
**N-Channel Logic Level Enhancement  
Mode Field Effect Transistor**
**P45N03LTG**

TO-220

Lead Free

**PRODUCT SUMMARY**

$V_{(BR)DSS}$	$R_{DS(ON)}$	$I_D$
25	20m	45A



1. GATE
2. DRAIN
3. SOURCE

**ABSOLUTE MAXIMUM RATINGS ( $T_C = 25^\circ\text{C}$  Unless Otherwise Noted)**

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$T_C = 25^\circ\text{C}$	$I_D$	45	A
	$T_C = 100^\circ\text{C}$		28	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	140	
Avalanche Current		$I_{AR}$	20	
Avalanche Energy	$L = 0.1\text{mH}$	$E_{AS}$	140	mJ
Repetitive Avalanche Energy <sup>2</sup>	$L = 0.05\text{mH}$	$E_{AR}$	5.6	
Power Dissipation	$T_C = 25^\circ\text{C}$	$P_D$	65	W
	$T_C = 100^\circ\text{C}$		33	
Operating Junction & Storage Temperature Range		$T_j, T_{stg}$	-55 to 150	°C
Lead Temperature ( $1/16$ " from case for 10 sec.)		$T_L$	275	

**THERMAL RESISTANCE RATINGS**

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Case	$R_{\theta JC}$	3	70	°C / W
Junction-to-Ambient	$R_{\theta JA}$			
Case-to-Heatsink	$R_{\theta CS}$			

<sup>1</sup>Pulse width limited by maximum junction temperature.<sup>2</sup>Duty cycle  $\leq 1\%$ **ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ , Unless Otherwise Noted)**

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
<b>STATIC</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	25			V
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	0.8	1.2	2.5	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\text{V}, V_{GS} = \pm 20\text{V}$			$\pm 250$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$			25	$\mu\text{A}$
		$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}, T_J = 125^\circ\text{C}$			250	

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On-State Drain Current <sup>1</sup>	I <sub>D(ON)</sub>	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 10V	45			A
Drain-Source On-State Resistance <sup>1</sup>	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 7V, I <sub>D</sub> = 18A		20	30	m
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 20A		15	28	
Forward Transconductance <sup>1</sup>	g <sub>fs</sub>	V <sub>DS</sub> = 15V, I <sub>D</sub> = 30A		16		S
<b>DYNAMIC</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 15V, f = 1MHz		600		pF
Output Capacitance	C <sub>oss</sub>			290		
Reverse Transfer Capacitance	C <sub>rss</sub>			100		
Total Gate Charge <sup>2</sup>	Q <sub>g</sub>	V <sub>DS</sub> = 0.5V <sub>(BR)DSS</sub> , V <sub>GS</sub> = 10V, I <sub>D</sub> = 20A		25		nC
Gate-Source Charge <sup>2</sup>	Q <sub>gs</sub>			2.9		
Gate-Drain Charge <sup>2</sup>	Q <sub>gd</sub>			7.0		
Turn-On Delay Time <sup>2</sup>	t <sub>d(on)</sub>			7.0		
Rise Time <sup>2</sup>	t <sub>r</sub>	V <sub>DS</sub> = 15V, R <sub>L</sub> = 1 I <sub>D</sub> ≈ 30A, V <sub>GS</sub> = 10V, R <sub>GS</sub> = 2.5		7.0		nS
Turn-Off Delay Time <sup>2</sup>	t <sub>d(off)</sub>			24		
Fall Time <sup>2</sup>	t <sub>f</sub>			6.0		
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (T<sub>C</sub> = 25 °C)</b>						
Continuous Current	I <sub>S</sub>	I <sub>F</sub> = I <sub>S</sub> , V <sub>GS</sub> = 0V I <sub>F</sub> = I <sub>S</sub> , dI <sub>F</sub> /dt = 100A / μS		45		A
Pulsed Current <sup>3</sup>	I <sub>SM</sub>				150	
Forward Voltage <sup>1</sup>	V <sub>SD</sub>				1.3	
Reverse Recovery Time	t <sub>rr</sub>			37		
Peak Reverse Recovery Current	I <sub>RM(REC)</sub>			200		
Reverse Recovery Charge	Q <sub>rr</sub>			0.043		

<sup>1</sup>Pulse test : Pulse Width ≤ 300 μsec, Duty Cycle ≤ 2%.<sup>2</sup>Independent of operating temperature.<sup>3</sup>Pulse width limited by maximum junction temperature.**REMARK: THE PRODUCT MARKED WITH “P45N03LTG”, DATE CODE or LOT #**

Orders for parts with Lead-Free plating can be placed using the PXXXXXXG parts name.

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**TO-220 (3-Lead) MECHANICAL DATA**

Dimension	mm			Dimension	mm		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	9.78	10.16	10.54	H	2.4	2.54	2.68
B	2.61	2.74	2.87	I	1.19	1.27	1.35
C		20		J	4.4	4.6	4.8
D	28.5	28.9	29.3	K	1.14	1.27	1.4
E	14.6	15.0	15.4	L	2.3	2.6	2.9
F	8.4	8.8	9.2	M	0.26	0.46	0.66
G	0.72	0.8	0.88	N		7°	

